

IR Transceiver Module

KODENSHI

KOI-6002AS

Features

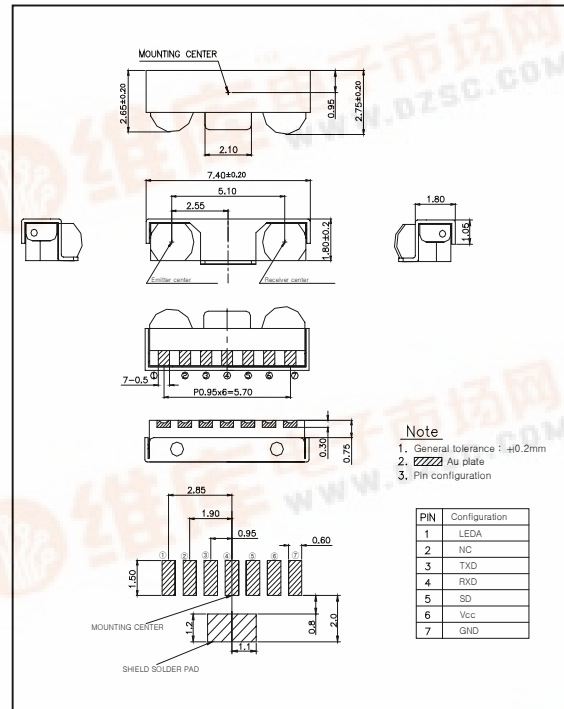
- Compliant to IrDA 1.4 Low Power Standard
- Wide Voltage Operation : 2.7 ~ 5.5V
- Compact Package Integrated Transmitter and Receiver
(7.4L x 2.75W x 1.8T)
- Complete Power Down Mode for the Current Consumption.
- Shielded Package for Preventing EMI
- LED Stuck-high Protection
- Lead-free & High reliability package

Applications

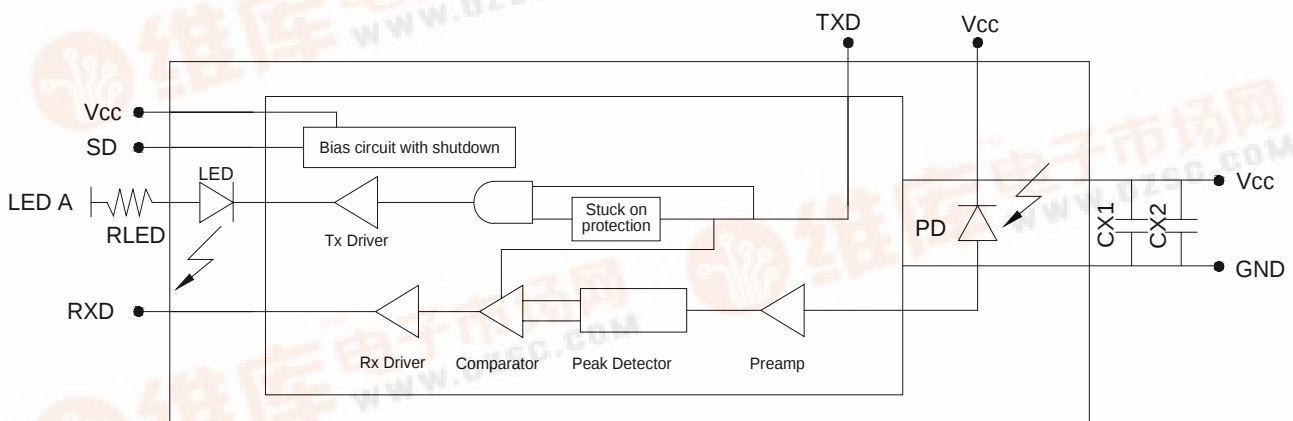
- Cellular Phone
- Personal Computer(Desk-top PC, Lap-top PC)
- Printers, Vending Machine, ATM
- Personal Digital Assistants.(PDA)

Dimensions

(Unit : mm)



Block Diagram



RLED $6.8\Omega \pm 5\%$, 0.25 Watt, LED A=2.7V
 RLED $10\Omega \pm 5\%$, 0.25 Watt, LED A=3.0V
 RLED $12\Omega \pm 5\%$, 0.25 Watt, LED A=3.6V
 RLED $16\Omega \pm 5\%$, 0.25 Watt, LED A=4.2V
 CX1 $0.47\mu\text{F} \pm 20\%$, Ceramic : CX2 $4.7\mu\text{F} \pm 20\%$, Tantalum
 CX1, CX2 must be placed 7mm of the KOI-6002AS

KOI-6002AS

Absolute Maximum Ratings

[Ta = 25°C]

Parameter	Symbol	Conditions	Min.	Max.	Unit
Supply Voltage	V _{CC}	-	0	6.5	V
LED Supply Voltage	V _{LED}	-	0	6.0	V
Operating Temperature	T _{opr.}	-	-20	85	°C
Storage Temperature	T _{stg.}	-	-40	100	°C
DC LED Transmit Current	I _{LED} (DC)	-	-	50	mA
Peak LED Transmit Current	I _{LED} (PK)	<90μs pulse width, <20% duty cycle	-	200	mA
Receiver Data Output Voltage	V _{RxD}	-	-0.5	V _{CC} +0.5	V
Transmitter Data Input Voltage	V _{TxD}	-	-0.5	V _{CC} +0.5	V
Data Rate	BR	-	9.6	115.2	kbit/s

4. Electro-Optical Characteristics

[Ta=25°C, V_{CC}=3.3V]

Parameter		Symbol	Conditions	Min.	Typ.	Max.	Unit
Supply Current		I _{cc1}	Shutdown	-	-	1	μA
		I _{cc2}	Idle	-	100	200	μA
Transmitter	Transmitter Wakeup Time	T _{tw}		-	30	200	μs
	Viewing Angle	2Θ _{1/2}	-	30	-	60	deg.
	Data Output Pulse Width	T _{stpw}	tpw(RxD)=1.63μs at 115.2kbit/s	1.6	1.7	1.9	μs
	Rise Time	t _r	BR=115.2kbit/s	-	20	600	ns
	Fall Time	t _f		-	20	600	ns
	Peak Emission Wavelength	λ _p	-	-	875	-	nm
	Spectral Bandwidth	Δλ	-	-	45	-	nm
Receiver	Viewing Angle	2Θ _{1/2}	-	30	-	60.0	deg.
	Peak Sensitivity Wavelength	λ _p	-	-	880	-	nm
	High Level Output Voltage	V _{OH}	I _{OH} =-20μA	V _{CC} -0.2	-	-	V
	Low Level Output Voltage	V _{OL}	I _{OL} =1mA	-	-	0.4	V
	Rx SIR Pulse Width	T _{srpw}	tpw(RxD)=1.63μs at 115.2kbit/s	1	2.2	4	μs
	Rise Time	t _r	BR=115.2kbit/s	-	80	600	ns
	Fall Time	t _f		-	40	600	ns
	Communication Distance	D		60	100	-	cm
	Receiver Latency Time	TL		-	100	150	μs
	Receiver Wakeup Time	T _{rw}		-	150	200	μs